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Robinson Intellectual Property Law Office			RUDE, TIMOTHY L	
PMB 955 21010 Southbar	nk Stret	·	ART UNIT	PAPER NUMBER
Potomac Falls,			2883	
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Please find below and/or attached an Office communication concerning this application or proceeding.

			an
	Application No.	Applicant(s)	
Office Action Cummons	09/619,479	YAMAZAKI ET AL.	
Office Action Summary	Examiner	Art Unit	
	Timothy L Rude	2883	
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with	the correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a repl - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailin earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply ly within the statutory minimum of thirty (3 will apply and will expire SIX (6) MONTH e, cause the application to become ABAN	be timely filed 0) days will be considered timely. 5 from the mailing date of this communication. DONED (35 U.S.C. § 133).	
Status			
 1) ☐ Responsive to communication(s) filed on 01 S 2a) ☐ This action is FINAL. 2b) ☐ This 3) ☐ Since this application is in condition for allowated closed in accordance with the practice under E 	s action is non-final. Ince except for formal matters	•	
Disposition of Claims			
 4) ☐ Claim(s) 1-25 and 29-37 is/are pending in the 4a) Of the above claim(s) is/are withdra 5) ☐ Claim(s) 10,11,21 and 22 is/are allowed. 6) ☐ Claim(s) 1-9,12-20,23-25 and 29-37 is/are rejection 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/or 	ected.		
Application Papers			
9) The specification is objected to by the Examine 10) The drawing(s) filed on is/are: a) accomposition and accomposition are accomposition. The oath or declaration is objected to by the Examine 10). The oath or declaration is objected to by the Examine 10.	cepted or b) objected to by drawing(s) be held in abeyance tion is required if the drawing(s)	See 37 CFR 1.85(a). is objected to. See 37 CFR 1.121(d).	•
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat* See the attached detailed Office action for a list	ts have been received. ts have been received in App rity documents have been re u (PCT Rule 17.2(a)).	ication No ceived in this National Stage	
Attachment(s) Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	r— -	mary (PTO-413) ail Date mal Patent Application (PTO-152)	

DETAILED ACTION

Claims

1. Claims 1, 4, 8, 10, 12, 15, 19, 21, and 23-25 are amended. Claims 26-28 are canceled.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

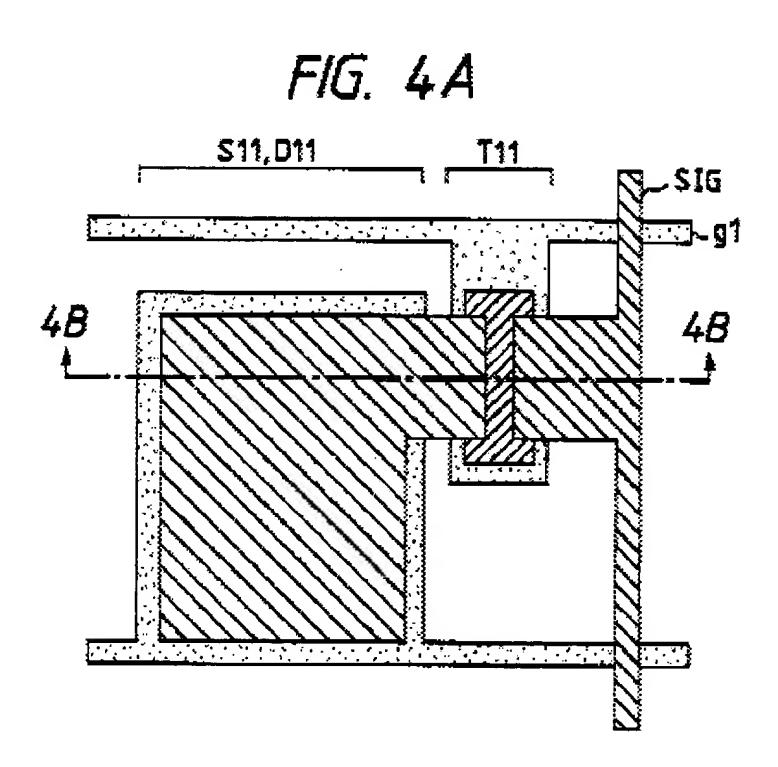
A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1, 2, 8, 12, 13, 19, 23, 25, 29, 31, 32, 34, 35, and 37 are rejected under 35 U.S.C. 102(b) as being anticipated by Kaifu et al (Kaifu) USPAT 5,812,109.

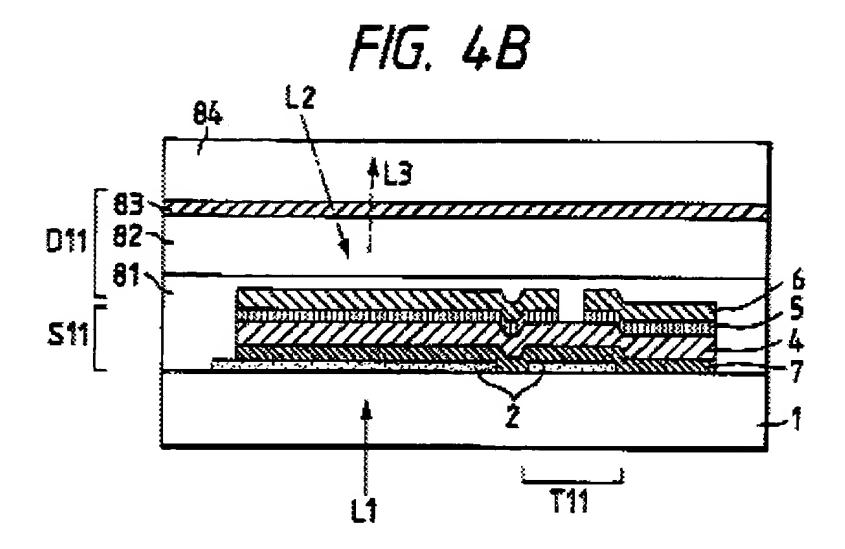
As to claims 1, 23, 25, and 29, Kaifu discloses an embodiment (col. 14, line 53 through col. 17, line 13) that is explained in part by Figures 3, 4A, and 4B, (col. 5, line 26 through col. 14, line 52) wherein an integral image recognition/display apparatus comprises: a plurality of pixel portions, (everything in Figure 4A), each having an active device, T11, and arranged in matrix and each having a pixel electrode (left portion in Figure 4B), comprising 10,000 angstrom thick layer of aluminum (Applicant's a reflecting material), 6, and n-doped silicon (Applicant's light-transmitting material), 5, (Applicant's pixel electrode comprises a first layer and a second layer, said second layer provided

Art Unit: 2883

over said first layer, one of said first layer and said second layer comprising a reflecting material (10,000 angstrom thick layer of aluminum) and the other comprising light-transmitting material (n-doped silicon)) over an active matrix substrate, 1; and a plurality of sensor portions, S11, arranged in matrix over said active matrix substrate, wherein said sensor portion includes a photo-electric conversion device, 4, and can read information by utilizing the rays of light transmitting through said light-transmitting material when an external image is read (Abstract), wherein said photo-electric conversion device, 4, overlaps the TFT (Applicant's active device).

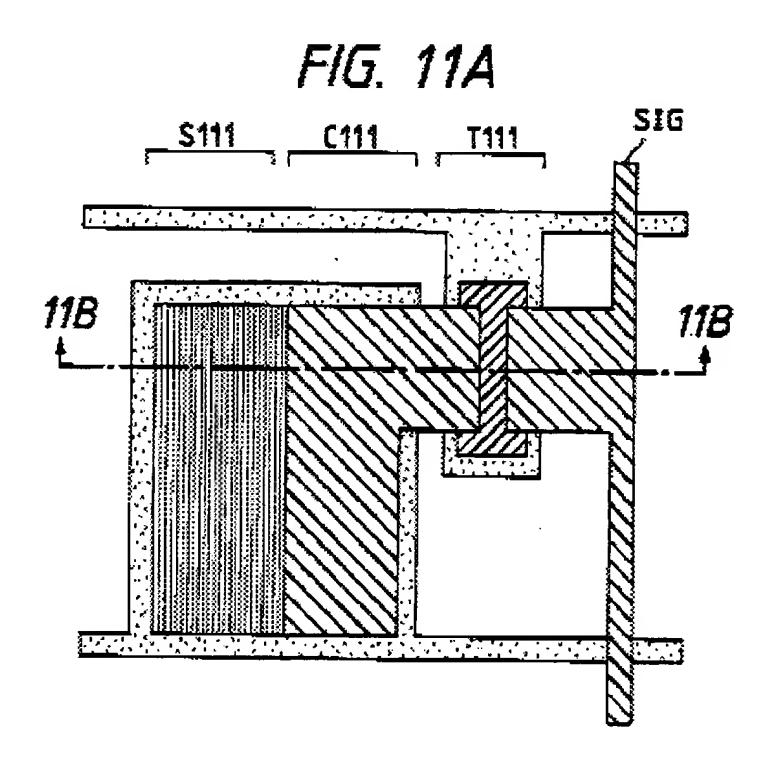


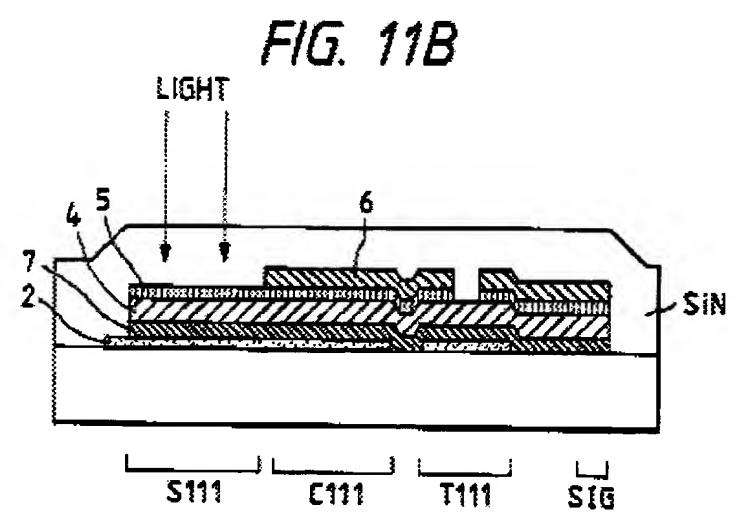
Art Unit: 2883



Note: the removal (col. 7, lines 12-22) of a portion of the aluminum electrode, 6, is not shown in Figures 4A and 4B. However, an illustration may be found in Figures 11A and 11B (Applicant's wherein a plane parallel to a direction of said matrix is divided into at least a first display region and a second display region in said pixel electrode, wherein said pixel electrode comprises a reflecting material, 6, in said first display region, and wherein said pixel electrode comprises a light-transmitting material, 5, in said second display region) (col. 14, line 53 through col. 17, line 13),

Art Unit: 2883





wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B). Please note: the difference between the embodiment of Figure 11B and that of Figures 4B is 11B performs the image input and display on the top side as opposed to 4B

Art Unit: 2883

performing the image input on the bottom side and the image display on the top side. Please also note: in Figure 11B pixel electrode, 6, is energized for image display which also necessarily energizes transparent n-type silicon structure, 5, that functions as a transparent pixel electrode in the display mode.

As to claim 2, Kaifu discloses in Figure 4B the apparatus according to claim 1, wherein said active device comprises a bottom gate type TFT, T11.

As to claim 8, Kaifu discloses in Figures 3, 4A, and 4B, an integral image recognition/display apparatus comprising: a plurality of pixel portions (everything in Figure 4A), each having an active device, T11, and arranged in matrix and each having a pixel electrode, (left portion in Figure 4B), comprising a reflecting material, 6, and a light-transmitting material, 5, over an active matrix substrate, 1; and a plurality of sensor portions, S11, arranged in matrix over said active matrix substrate, wherein said sensor portion has a photo-electric conversion device, 4, and at least a part of said photo-electric conversion device, 4, is extended in such a manner as to overlap with said active device, T11, wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B).

As to claim 12, Kaifu discloses in Figures 3, 4A, and 4B, a semiconductor device comprising: a pixel portion, (everything in Figure 4A), having an active device, T11, and

Art Unit: 2883

a pixel electrode comprising a reflecting material, 6, and a light-transmitting material, 5, over an active matrix substrate; and a sensor portion, S11, provided over said active matrix substrate, 1; and comprising a photo-electric conversion device, 4, wherein said active device and said pixel electrode and said photo-electric conversion device are provided in one of pixels arranged in matrix, and wherein said sensor portion can read information by utilizing the rays of light transmitting through said light-transmitting material when an external image is read (Abstract), wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B).

As to claim 13, Kaifu discloses in Figure 4B the apparatus according to claim 12, wherein said active device comprises a bottom gate type TFT, T11.

As to claim 19, Kaifu discloses in Figures 3, 4A, and 4B, a semiconductor device comprising: a pixel portion, (everything in Figure 4A), having an active device, T11, and a pixel electrode comprising a reflecting material, 6, and a light-transmitting material, 5, over an active matrix substrate, 1; and a sensor portion, S11, provided over said active matrix substrate and having a photo-electric conversion device, 4, wherein said active device and said pixel electrode and said photo-electric conversion device are provided in one of pixels arranged in matrix, and wherein at least a part of said photo-electric conversion device, 4, is extended in such a manner as to overlap with said active device, T11, wherein said pixel electrode, 6, has an image display function (col. 11, line

Art Unit: 2883

66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

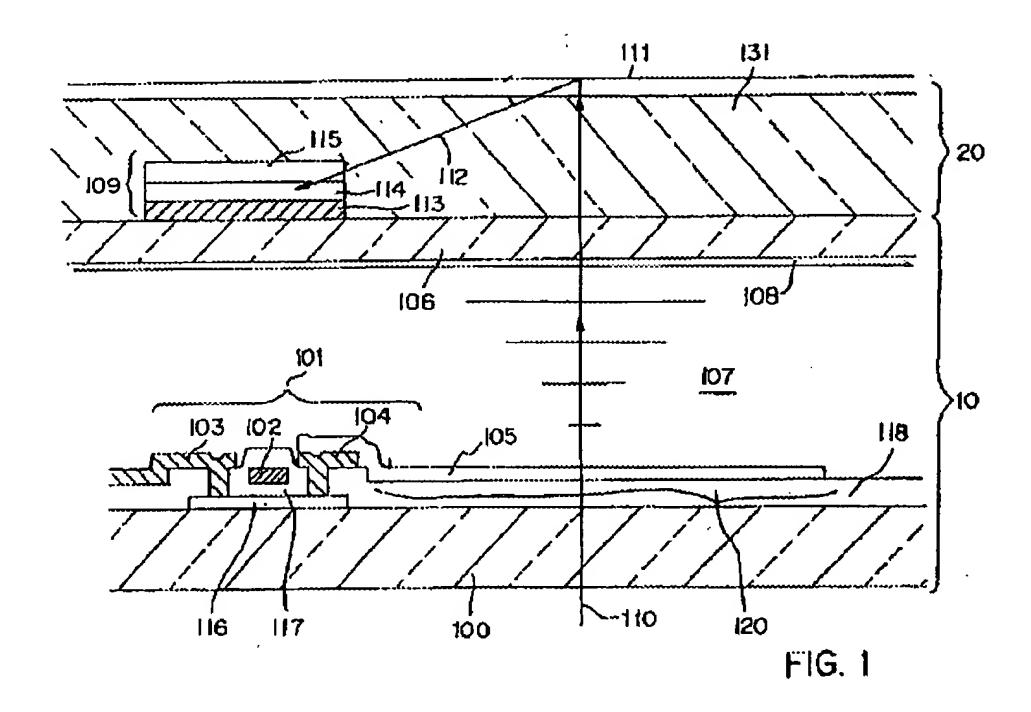
- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 3-7, 9, 14-18, 20, 24, 30, 33, and 36 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kaifu in view of Itoh et al (Itoh) USPAT 5,585,817.

As to claim 3, Kaifu discloses the apparatus according to claim 1.

Kaifu does not explicitly disclose the use of a top gate type TFT.

Itoh teaches the use of a top gate TFT, 101, in an integral image recognition/display apparatus in Figure 1 as an art recognized means suitable for the intended purpose of comprising a TFT for improved switching (turning on and off) of the pixel electrodes (MPEP 2144.07) (col. 5, lines 3-11).

Art Unit: 2883



Itoh is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add top gate TFTs as an art recognized means suitable for the intended purpose of comprising a TFT for improved switching of the pixel electrodes (col. 5, lines 3-11).

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the integral image recognition/display apparatus of Kaifu with the top gate TFTs of Itoh as an alternate means providing design and manufacturing flexibility for improved switching of the pixel electrodes.

As to claims 4 and 30, Kaifu discloses in Figures 3, 4A, and 4B, an integral image recognition/display apparatus comprising: a plurality of pixel portions, (everything in Figure 4A), each having an active device, T11, and arranged in matrix

Art Unit: 2883

and each having a pixel electrode (left portion in Figure 4B), comprising a reflecting material, 6, and a light-transmitting material, 5, over an active matrix substrate, 1, wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B), wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B).

Kaifu does not explicitly disclose a plurality of sensor portions disposed in matrix over an opposed substrate constituting a display panel, wherein said sensor portion has a photo-electric conversion device, and can read information by utilizing the rays of light transmitting through said light-transmitting material when an external image is read.

Itoh teaches in Figure 1 the use of a plurality of sensor portions, 109, disposed in matrix over an opposed substrate, 106, constituting a display panel, wherein said sensor portion has a photo-electric conversion device (col. 4, lines 36-42), and can read information by utilizing the rays of light, 110, transmitting through said light-transmitting material when an external image, 111, is read.

Itoh is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add photo-electric conversion devices to the opposed substrate to improve contrast (col. 4, lines 56-60).

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the integral image recognition/display apparatus of Kaifu with photo-electric conversion devices on the opposed substrate of Itoh to improve contrast for superior image display.

Art Unit: 2883

As to claim 5, Kaifu discloses the invention of a full color device (col. 19, lines 41-47).

Kaifu in view of Itoh does not explicitly disclose color filters disposed on the opposed substrate. However, the use of color filters on the opposed substrate is one of the most common configurations in the art of liquid crystals to simplify manufacture.

Kaifu is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add color filters to the opposed substrate to facilitate a full color display.

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the integral image recognition/display apparatus of Kaifu in view of Itoh with the color filters of Kaifu to provide a full color display.

As to claim 6, Kaifu discloses in Figure 4B the use of a bottom gate type TFT, T11.

As to claims 7, 9, 14, 18, and 20, Kaifu discloses the apparatus above.

Kaifu does not explicitly disclose the use of a top gate type TFT.

Itoh teaches the use of a top gate TFT, 101, in an integral image recognition/display apparatus in Figure 1 as an art recognized means suitable for the

Art Unit: 2883

intended purpose of comprising a TFT for improved switching (turning on and off) of the pixel electrodes (MPEP 2144.07) (col. 5, lines 3-11).

Itoh is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add top gate TFTs as an art recognized means suitable for the intended purpose of comprising a TFT for improved switching of the pixel electrodes (col. 5, lines 3-11).

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the integral image recognition/display apparatus of Kaifu with the top gate TFTs of Itoh as an alternate means providing design and manufacturing flexibility for improved switching of the pixel electrodes.

As to claims 15, 24, 33, and 36, Kaifu discloses in Figures 3, 4A, and 4B, a semiconductor device comprising: an active matrix substrate, 1, and an opposed substrate, 84; a pixel portion having an active device, T11, and a pixel electrode comprising a reflecting material, 6, and a light-transmitting material, 5, over said active matrix substrate wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B), wherein said pixel electrode, 6, has an image display function (col. 11, line 66 through col. 12, line 10; see also incident light ray L2 and reflected light ray L3 in Figure 4B).

Art Unit: 2883

Kaifu does not explicitly disclose a sensor portion provided over said opposed substrate and comprising a photo-electric conversion device, wherein said active device and said pixel electrode and said photo-electric conversion device are provided in one of pixels arranged in matrix, (wherein said active device and said pixel electrode and said photo-electric conversion device are provided in one of pixels arranged in matrix,) and wherein said sensor portion can read information by utilizing the rays of light transmitting through said light-transmitting material when an external image is read.

Itoh teaches in Figure 1 the use of a plurality of sensor portions, 109, disposed in matrix over an opposed substrate, 106, constituting a display panel, wherein said sensor portion has a photo-electric conversion device (col. 4, lines 36-42), and can read information by utilizing the rays of light, 110, transmitting through said light-transmitting material when an external image, 111, is read.

Itoh is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add photo-electric conversion devices to the opposed substrate to improve contrast (col. 4, lines 56-60).

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the integral image recognition/display apparatus of Kaifu with photo-electric conversion devices on the opposed substrate of Itoh to improve contrast for superior image display.

As to claim 16, Kaifu discloses the invention of a full color device (col. 19, lines 41-47).

Art Unit: 2883

Kaifu in view of Itoh does not explicitly disclose color filters disposed on the opposed substrate. However, the use of color filters on the opposed substrate is one of the most common configurations in the art of liquid crystals to simplify manufacture.

Kaifu is evidence that ordinary workers in the art of liquid crystals would find the reason, suggestion, or motivation to add color filters to the opposed substrate to facilitate a full color display.

Therefore, it would have been obvious to one having ordinary skill in the art of liquid crystals at the time the invention was made to modify the integral image recognition/display apparatus of Kaifu in view of Itoh with the color filters of Kaifu to comprise a full color display.

As to claim 17, Kaifu discloses in Figure 4B the use of a bottom gate type TFT, T11.

Allowable Subject Matter

4. Claims 10, 11, 21, and 22 are allowed.

The following is a statement of reasons for the indication of allowable subject matter:

As to claims 10 and 21, relevant prior art of record did not disclose, alone or in combination, a device as claimed comprising: "an insulation film provided over said

with one of a source region and a drain region of said transistor; wherein said pixel

electrode overlaps with said upper electrode with said insulation film therebetween to

provide a capacitance." The closest reference is Kaifu, but Kaifu does not disclose a

pixel electrode separated from the upper electrode by an insulating film.

As to claims 11 and 22, they are dependent upon claims with allowable subject matter above.

Response to Arguments

5. Applicant's arguments filed on 01 September 2004 have been fully considered but they are not persuasive.

Applicant's ONLY arguments are as follows:

Kaifu does not disclose an apparatus comprising a plurality of pixel portions each comprising an active device.

Examiner's responses to Applicant's ONLY arguments are as follows:

It is respectfully pointed out that Kaifu discloses an apparatus comprising a plurality of pixel portions (everything in Figure 4A) each comprising an active device, T11, per rejections above.

Art Unit: 2883

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Timothy L Rude whose telephone number is (571) 272-2301. The examiner can normally be reached on Monday through Thursday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Frank Font can be reached on (571) 272-2415. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

tlr

Timothy L Rude Examiner Art Unit 2883

Frank St For

Frank G. Font Supervisory Patent Examiner Technology Center 2800